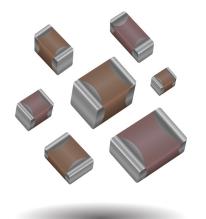
MLCC Medical Applications – MM Series

General Specifications





The AVX MM series is a multi-layer ceramic capacitor designed for use in medical applications other than implantable/life support. These components have the design & change control expected for medical devices and also offer enhanced LAT including reliability testing and 100% inspection.

APPLICATIONS

- Implantable, Non-Life Supporting Medical Devices
- e.g. implanted temporary cardiac monitor, insulin pumps

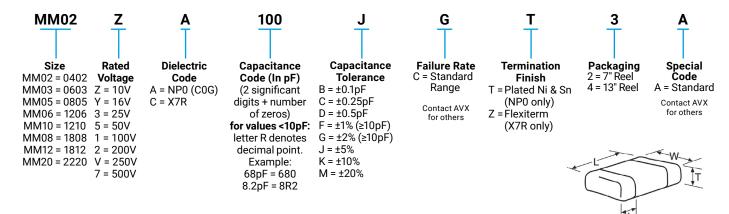
External, Life Supporting Medical Devices

• e.g. heart pump external controller

External Devices

• e.g. patient monitoring, diagnostic equipment

HOW TO ORDER



COMMERCIAL VS MM SERIES PROCESS COMPARISON

	Commercial	MM Series					
Administrative	Standard part numbers; no restriction on who purchases these parts	Specific series part number, used to control supply of product					
Design	Minimum ceramic thickness of 0.020" on all X7R product	Minimum ceramic thickness of 0.022" (0.56mm)					
Dicing	Side & end margins = 0.003" min	Side & end margins = 0.004" min Cover layers = 0.003" min					
Lot Qualification Destructive Physical Analysis (DPA)	As per EIA RS469	Increased sample plan – stricter criteria					
Visual/Cosmetic Quality	Standard process and inspection	100% inspection					
Application Robustness	Standard sampling for accelerated wave solder on X7R dielectrics	Increased sampling for accelerated wave solder on X7R and NP0 followed by lot by lot reliability testing					
Design/Change Control	Required to inform customer of changes in: • form • fit • function	 AVX will qualify and notify customers before making any change to the following materials or processes: Dielectric formulation, type, or supplier Metal formulation, type, or supplier Termination material formulation, type, or supplier Manufacturing equipment type Quality testing regime including sample size and accept/ reject criteria 					



The Important Information/Disclaimer is incorporated in the catalog where these specifications came from or available online at www.avx.com/disclaimer/ by reference and should be reviewed in full before placing any order.

NP0 (C0G) - Specifications & Test Methods



Parame	ter/Test	NP0 Specification Limits	Measuring	Conditions					
	perature Range	-55°C to +125°C	Temperature C	ycle Chamber					
Capac	itance	Within specified tolerance	Freq.: 1.0 MHz ± 109	% for cap ≤ 1000 pF					
(2	<30 pF: Q≥ 400+20 x Cap Value ≥30 pF: Q≥ 1000	1.0 kHz ± 10% fo Voltage: 1.0	Vrms ± .2V					
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with 60 ± 5 secs @ room	n rated voltage for m temp/humidity					
Dielectric	Strength	No breakdown or visual defects	1-5 seconds, w/charge limited to 50 Note: Charge device with	Charge device with 300% of rated voltage for -5 seconds, w/charge and discharge current limited to 50 mA (max) ote: Charge device with 150% of rated voltage for 500V devices.					
	Appearance	No defects	Deflectio	n [.] 2mm					
Resistance to	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Test Time: 3						
Flexure Stresses	Q	Meets Initial Values (As Above)							
	Insulation Resistance	≥ Initial Value x 0.3	90 r						
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.1						
	Appearance	No defects, <25% leaching of either end terminal	-						
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater							
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2						
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties					
	Dielectric Strength	Meets Initial Values (As Above)							
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes					
	Capacitance Variation	\leq ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes					
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes					
Chieda	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp ≤ 3 minutes						
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 hours at room						
	Appearance	No visual defects	-						
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twice rated voltage in test						
Load Life	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	chamber set at 125°C ± 2°C for 1000 hours (+48, -0).						
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test cha room temperatu before me	re for 24 hours					
	Dielectric Strength	Meets Initial Values (As Above)		acarnig.					
	Appearance	No visual defects							
	Capacitance Variation	\leq ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber	cat at 85°C + 2°C / 05					
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	± 5% relative humid (+48, -0) with rated	lity for 1000 hours I voltage applied.					
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature for 24 ± 2 h						
	Dielectric Strength	Meets Initial Values (As Above)							



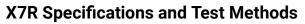


NP0/C0G Capacitance Range

PREFERRED SIZES ARE SHADED

SIZI	E		06	603				0805	1206									
	WVDC	16	25	50	100	16	25	50	100	16	25	50	100					
Cap 0.5	0R5																	
(pF) 1.0	1R0																	
1.2																		
1.5	1R5																	
1.8	1R8																	
2.2	2R2																	
2.7	2R7																	
3.3	3R3																	
3.9																		
4.7																		
5.6																		
6.8																		
8.2																		
10																		
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56																		
68																		
82																		
100																		
120																		
150																		
180																		
220																		
270																		
330																		
390																		
470																		
560																		
680																		
820																		
1000																		
1200																		
1500	152																	
WVD		16	25	50	100	16	25	50	100	16	25	50	100					
SIZI	E		06	603				0805				1206						







Parame	ter/Test	X7R Specification Limits	Measuring (Conditions							
		-55°C to +125°C	Temperature C	ycle Chamber							
Capac	itance	Within specified tolerance									
C	2	≤ 10% for ≥ 50V DC rating ≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Freq.: 1.0 kHz ± 10% Voltage: 1.0Vrms ± .2V								
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with rated voltage for 120 ± 5 secs @ room temp/humidity								
Dielectric	Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.								
	Appearance	No defects	Deflectio	n [.] 2mm							
Resistance to	Capacitance Variation Dissipation Factor Insulation Resistance Capacitance Variation Dissipation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Dissipation Factor Insulation Resistance Dielectric Strength Dissipation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Resistance Dielectric Strength Appearance Capacitance Variation Resistance Dielectric Strength Appearance Capacitance Variation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Resistance Dielectric Strength	≤ ±12%	Test Time: 3								
Flexure Stresses		Meets Initial Values (As Above)									
		≥ Initial Value x 0.3	90 mm								
Solder	ability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5								
		No defects, <25% leaching of either end terminal									
	Variation	≤ ±7.5%									
Resistance to	Factor	Meets Initial Values (As Above)	Dip device in eutectic solder at 260° C for 60 seconds. Store at room temperature for 24 ± 2								
Flexure Stresses Solder		Meets Initial Values (As Above)	hours before measuring	g electrical properties.							
		Meets Initial Values (As Above)									
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes							
	Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes							
	Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes							
		Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes							
		Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro								
		No visual defects									
		≤ ±12.5%	Charge device with 1.5 r test chamber set								
Load Life		≤ Initial Value x 2.0 (See Above)	for 1000 hours (+48, -0)								
		≥ Initial Value x 0.3 (See Above)	Remove from test chamber and stabilize at room temperature for 24 ± 2 hours before								
		Meets Initial Values (As Above)	measu	iring.							
	Appearance	No visual defects									
		≤ ±12.5%	Store in a test chamber s								
Load		≤ Initial Value x 2.0 (See Above)	± 5% relative humidity for 1000 hours (+48, -0) with rated voltage applied.								
Humidity	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an	d humidity for							
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours bef	ore measuring.							



X7R Capacitance Range

PREFERRED SIZES ARE SHADED

	SIZE			040)2	0603										080)5						12	06							12	10				1	80	8		18	312		222	0	
		WVDC	16	25	50	10	16	5 2	5	50	100	200	10	16	25	50	100	200	250	10	16	25	50	100	200	250	500	10	16	25	50	100	200	250	500	50	100	200	50	100	200	250	25	50	100
Cap	220	221						1																																					
(pF)	270	271																													1									1					
	330	331																																											
	390	391																											1														1	1	
	470	471					Τ																1								1														
	560	561																					1						1		1													1	
	680	681																																											
	820	821																																											
	1000	102																																											
	1200	122																																											
	1500	152																													1										1				
	1800	182							Т																																				
	2200	222																																											
	2700	272																																											
	3300	332																																											
	3900	392																																											
	4700	472																																											
	5600	562																																											
	6800	682																																											
	8200	822																																											
сар	0.010	103																																											
uF	0.012	123			1				Т																																				
	0.015	153																																											
	0.018	183																																											
	0.022	223																																											
	0.027	273																																											
	0.033	333																																											
	0.039	393																																											
	0.047	473																																											
	0.056	563																																											
	0.068	683																																											
	0.082	823																																											
	0.10	104							T																																				
	0.12	124																																											
	0.15	154							T																																				
	0.22	224						T	T																																				
	0.33	334																																											
	0.47	474																																											
	0.56	564						Γ																																					
	0.68	684																																											
	0.82	824																																											
	1.0	105							Ι																																				
	1.2	125																																											
	1.5	155							Τ																																				
	WVDC	:	16	25	50	10	16	5 2	5	50	100	200	10	16	25	50	100	200	250	10	16	25	50	100	200	250	500	10	16	25	50	100	200	250	500	50	100	200	50	100	200	250	25	50	100
	SIZE			040	2		0603									080)5						12	06							12	10				1	80	8		18	312			222	0

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 MM031C103KCZ2A
 MM035C104KCZ2A
 MM035C223KCZ2A
 MM051C103KCZ2A

 MM062C102KCZ2A
 MM102C104KCZ2A
 MM035C104KCZ2A
 MM035C223KCZ2A
 MM051C103KCZ2A